

4 Functionality

4.1 Power modes

The LIS2MDL provides two different power modes: high-resolution and low-power modes.

The tables below summarize the RMS noise values and current consumption in different product configurations.

When the low-pass filter is enabled, the bandwidth is reduced while noise performance is improved without any increase in power consumption.

Table 10. RMS noise of operating modes

CFG_REG_B[LPF] or CFG_REG_B[OFF_CANC]	(CFG_REG_A[LP = 0]) high-resolution mode		(CFG_REG_A[LP = 1]) low-power mode	
	BW [Hz]	Noise RMS [mg]	BW [Hz]	Noise RMS [mg]
0 (disable)	ODR/2	4.5	ODR/2	9
1 (enable)	ODR/4	3	ODR/4	6

Table 11. Current consumption of operating modes

ODR (Hz)	Current consumption (μ A) (CFG_REG_A [LP] = 0) high-resolution CFG_REG_B [OFF_CANC] = 0	Current consumption (μ A) (CFG_REG_A [LP] = 1) low-power CFG_REG_B [OFF_CANC] = 0	Current consumption (μ A) (CFG_REG_A [LP] = 0) high-resolution CFG_REG_B [OFF_CANC] = 1	Current consumption (μ A) (CFG_REG_A [LP] = 1) low-power CFG_REG_B [OFF_CANC] = 1
10	100	25	120	50
20	200	50	235	100
50	475	125	575	235
100	950	250	1130	460

Accelerometer

POWER SUPPLY					
Operating Voltage Range (V _S)		2.0	2.5	3.6	V
Interface Voltage Range (V _{DD I/O})		1.7	1.8	V _S	V
Supply Current	ODR ≥ 100 Hz		140		μA
	ODR < 10 Hz		30		μA
Standby Mode Leakage Current			0.1		μA
Turn-On and Wake-Up Time ⁷	ODR = 3200 Hz		1.4		ms

Microcontroller

PIC18F2585/2680/4585/4680

27.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (†)

Ambient temperature under bias	-40°C to +125°C
Storage temperature	-65°C to +150°C
Voltage on any pin with respect to V _{SS} (except V _{DD} and MCLR)	-0.3V to (V _{DD} + 0.3V)
Voltage on V _{DD} with respect to V _{SS}	-0.3V to +7.5V
Voltage on MCLR with respect to V _{SS} (Note 2)	0V to +13.25V
Total power dissipation (Note 1)	1.0W
Maximum current out of V _{SS} pin	300 mA
Maximum current into V _{DD} pin	250 mA
Input clamp current, I _{IK} (V _I < 0 or V _I > V _{DD})	±20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{DD})	±20 mA
Maximum output current sunk by any I/O pin	25 mA
Maximum output current sourced by any I/O pin	25 mA
Maximum current sunk by all ports	200 mA
Maximum current sourced by all ports	200 mA

- Note 1:** Power dissipation is calculated as follows:
 $P_{dis} = V_{DD} \times (I_{DD} - \sum I_{OH}) + \sum \{(V_{DD} - V_{OH}) \times I_{OH}\} + \sum (V_{OL} \times I_{OL})$
- 2:** Voltage spikes below V_{SS} at the MCLR/VPP pin, inducing currents greater than 80 mA, may cause latch-up. Thus, a series resistor of 50-100Ω should be used when applying a "low" level to the MCLR/VPP/RE3 pin, rather than pulling this pin directly to V_{SS}.

GPS Module

Electrical Specification

Absolute Maximums Ratings

Parameter	Min.	Typ.	Max.	Conditions	Unit
POWER Supply					
Main power supply(VCC)	4.5	5.0	6.5		V
Main power supply Current	45	50	55	GPS is not 3D Fixed.	mA
	33	34	38	GPS is 3D Fixed.	mA
RF					
Operating Frequency		1.575			Ghz

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EM-506
High Performance GPS Module



DC Electrical characteristics

Parameter	Symbol	Min.	Typ.	Max.	Conditions	Units
I/O Low Level Output Voltage	V _{OL}			0.4		V
I/O High Level Output Voltage	V _{OH}		3.3			V
I/O Low Level Input Voltage	V _{IL}	-0.4		0.45		V
I/O High Level Input Voltage	V _{IH}	1.26		3.6		V
High Level Output Current	I _{OH}		2			mA
Low Level Output Current	I _{OL}		2			mA